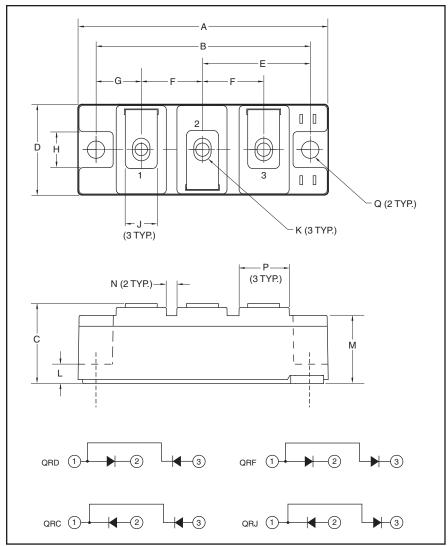


Super Fast Recovery Diode Modules 210 Amperes/1200 Volts



Outline Drawing and Circuit Diagram

Dimensions	Millimeters
Α	94
В	80
С	30
D	34
E	40
F	23
G	17
Н	13

Dimensions	Millimeters	
J	12	
K	M6	
L	7.5	
М	25.4	
N	4	
Р	19	
Q	6.5 Dia.	
	·	



Description:

Powerex Super Fast Recovery Dual Diode Modules are designed for use in applications requiring fast switching. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- ☐ Super Fast Recovery Time
- ☐ RoHS Compliant
- ☐ Isolated Mounting
- ☐ Metal Baseplate
- ☐ Low Thermal Impedance
- ☐ 2500V Isolating Voltage

Applications:

- ☐ Free Wheeling
- ☐ Welding and Plasma Cutting Machine



QR_1230R30 Super Fast Recovery Dual Diode Modules 210 Amperes/1200 Volts

Absolute Maximum Ratings, $T_i = 25$ °C unless otherwise specified

		QRD1230R30	
		QRF1230R30	
Ratings	Symbol	QRJ1230R30	Units
Repetitive Peak Reverse Blocking Voltage	V_{RRM}	1200	Volts
Non-Repetitive Peak Reverse Blocking Voltage	V_{RSM}	V _{RRM} + 100	Volts
DC Current, T _C = 80°C (Resistive Load)	I _{F(DC)}	210	Amperes
Peak Half Cycle Non-repetitive Surge Current (t = 8.3mS, 100% V _{RRM} Reapplied)	I _{FSM}	2550	Amperes
I ² t for Fusing for One Cycle (t = 8.3mS, 100% V _{RRM} Reapplied)	I ² t	27,000	A ² sec
Operating Junction Temperature	Tj	-40 to 150	°C
Storage Temperature	T _{stg}	-40 to 150	°C
Maximum Mounting Torque, M6 Mounting Screw	_	26	in-lb
Maximum Mounting Torque, M6 Terminal Screw	_	26	in-lb
Module Weight (Typical)	_	180	Grams
V Isolation (60 Hz, Circuit to Base, All Terminals Shorted, t = 60 sec)	V _{RMS}	2500	Volts

Electrical Characteristics, $T_i = 25$ °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Reverse Leakage Current	I _{RRM}	Rated V _{RRM}	_	_	1.0	mA
On-State Voltage	V_{FM}	I _F = 150A	_	2.4	3.2	Volts
		I _F = 210A	_	2.7	3.5	Volts
Threshold Voltage	V _{TO}	T _j = 125°C	_	2.20	_	Volts
Slope Resistance	r _T	T _j = 125°C	_	5.02	_	mΩ
Reverse Recovery Time	t _{rr}	V _{RM} = 600V,	_	110	_	ns
Reverse Recovery Charge	Q _{rr}	I _F = 210A, di/dt = -600 A/μs	_	13.8	_	μC
Reverse Recovery Energy	E _{rec}	 T _i = 125°C	_	23	_	mJ/Pulse

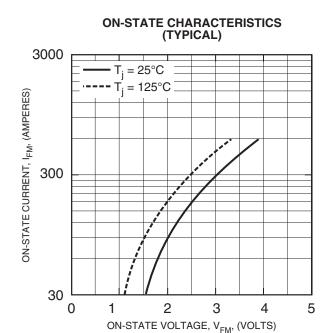
Thermal and Mechanical Characteristics, $T_j = 25$ °C unless otherwise specified

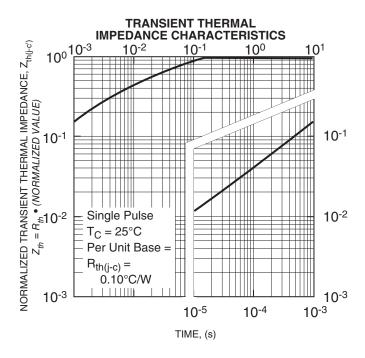
Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal Resistance, Junction to Case*	R _{th(j-c)} Q	Per Diode	_	_	0.10	°C/W
Contact Thermal Resistance, Case to Sink	R _{th(c-s)}	Per Module	_	_	0.05	°C/W
(Lubricated)*						

 $^{{}^{\}star}T_{C}$, T_{f} measured point is just under the chip.

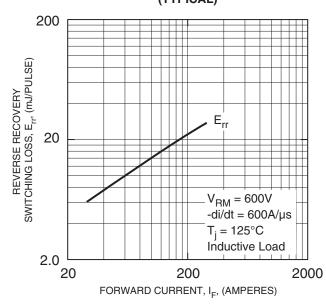


QR_1230R30 Super Fast Recovery Dual Diode Modules 210 Amperes/1200 Volts

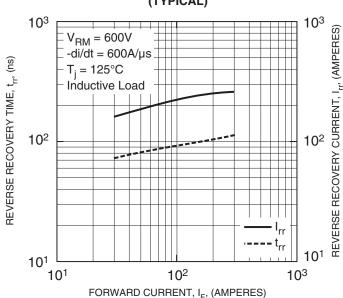




REVERSE RECOVERY SWITCHING LOSS CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)





QR_1230R30 Super Fast Recovery Dual Diode Modules 210 Amperes/1200 Volts

